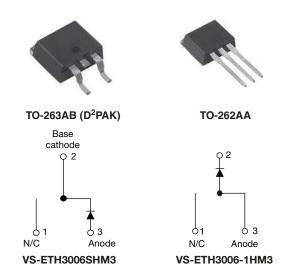


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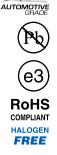
Hyperfast Rectifier, 30 A FRED Pt[®]



PRODUCT SUMMARY	
Package	TO-263AB (D ² PAK), TO-262AA
I _{F(AV)}	30 A
V _R	600 V
V _F at I _F	1.4 V
t _{rr} (typ.)	27 ns
T _J max.	175 °C
Diode variation	Single die

FEATURES

- Hyperfast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- AEC-Q101 qualified, meets JESD 201 class 1A whisker test



- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC Boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Repetitive peak reverse voltage	V _{RRM}		600	V			
Average rectified forward current	I _{F(AV)}	T _C = 95 °C	30	А			
Non-repetitive peak surge current	I _{FSM}	$T_{\rm C} = 25 \ ^{\circ}{\rm C}$	180	A			
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-			
	V	I _F = 30 A	-	2.0	2.65	V		
Forward voltage	V _F	I _F = 30 A, T _J = 150 °C	-	1.4	1.8			
Poveroo lookogo ourrent	I _R	V _R = V _R rated	-	0.02	30			
Reverse leakage current		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	50	300	μA		
Junction capacitance	CT	V _R = 600 V	-	20	-	pF		
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH		

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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1 \text{ A}, dI_F/dt = 50$	0 A/µs, V _R = 30 V	-	26	35			
Reverse recovery time	t _{rr}	T _J = 25 °C		-	26	-	ns		
		T _J = 125 °C	I _F = 30 A dI _F /dt = 200 A/μs V _R = 200 V	-	70	-			
Peak recovery current	I _{RRM}	T _J = 25 °C		-	3.5	-	A		
Feak recovery current		T _J = 125 °C		-	7.6	-			
	0	T _J = 25 °C		-	50	-	nC		
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	280	-	пс		

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C	
Thermal resistance, junction to case	R _{thJC}		-	0.95	1.4	°C/W	
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	70		
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-		
Weight			-	2.0	-	g	
Weight			-	0.07	-	oz.	
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)	
Marking dovice		Case style TO-263AB (D ² PAK)	ETH3006SH				
Marking device		Case style TO-262AA		ETH3006-1H			



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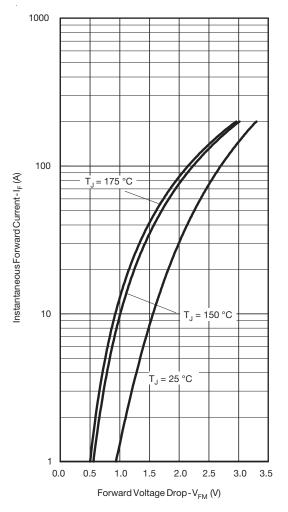


Fig. 1 - Typical Forward Voltage Drop Characteristics

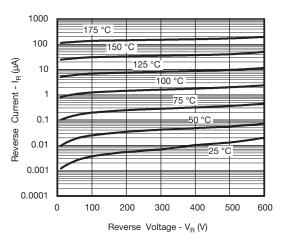


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

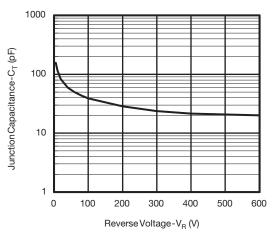


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

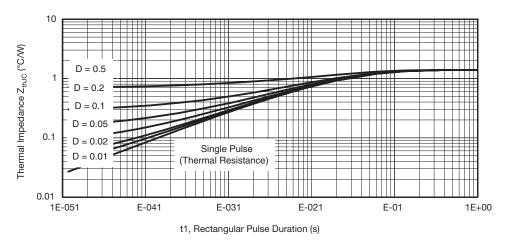
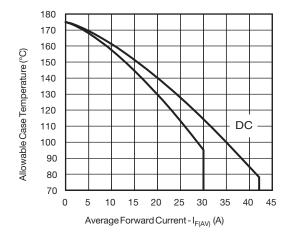
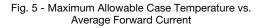


Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics



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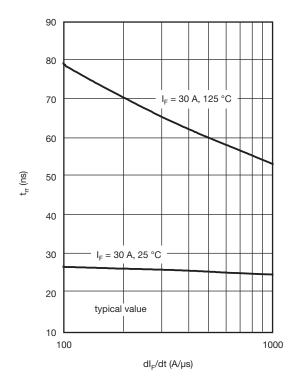


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

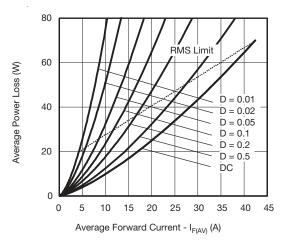


Fig. 6 - Forward Power Loss Characteristics

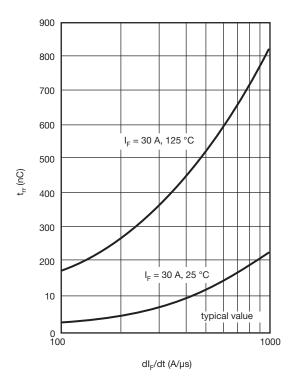


Fig. 8 - Typical Stored Charge vs. dl_F/dt



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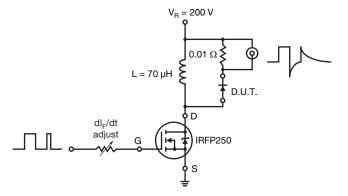


Fig. 9 - Reverse Recovery Parameter Test Circuit

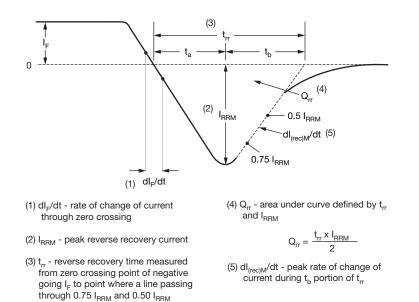
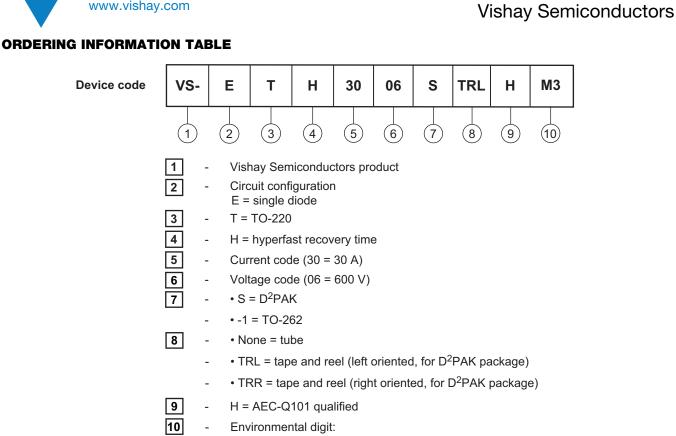


Fig. 10 - Reverse Recovery Waveform and Definitions

extrapolated to zero current.



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-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

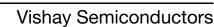
VS-ETH3006SHM3, VS-ETH3006-1HM3

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-ETH3006SHM3	50	1000	Antistatic plastic tube				
VS-ETH3006-1HM3	50	1000	Antistatic plastic tube				
VS-ETH3006STRRHM3	800	800	13" diameter reel				
VS-ETH3006STRLHM3	800	800	13" diameter reel				

LINKS TO RELATED DOCUMENTS						
Dimensions	TO-263AB (D ² PAK)	www.vishay.com/doc?95046				
	TO-262AA	www.vishay.com/doc?95419				
Part marking information	TO-263AB (D ² PAK)	www.vishay.com/doc?95444				
Fait marking information	TO-262AA	www.vishay.com/doc?95443				
Packaging information	TO-263AB (D ² PAK)	www.vishay.com/doc?95032				

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Outline Dimensions

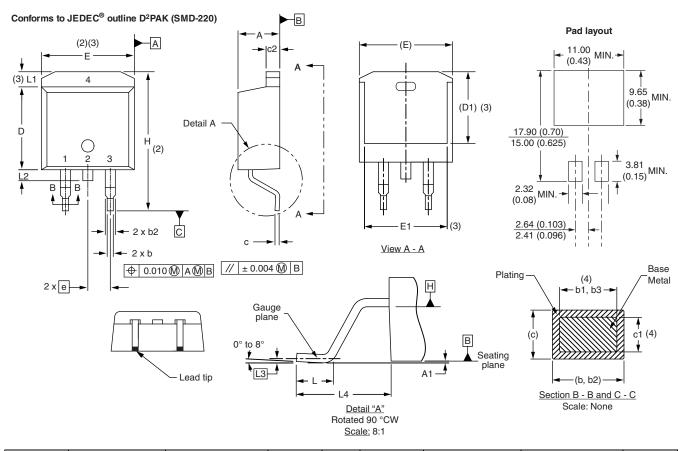


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D²PAK

DIMENSIONS in millimeters and inches

SHA



SYMBOL	MILLIM	METERS INCHES		NOTES		SYMBOL	MILLIM	IETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010) BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 08-Jul-15

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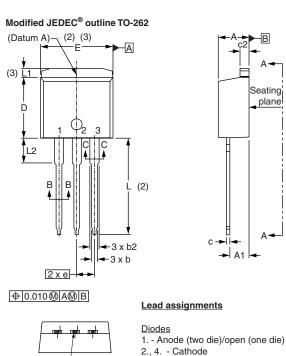
Outline Dimensions



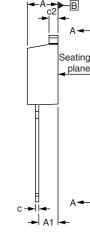
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TO-262

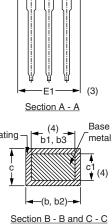
DIMENSIONS in millimeters and inches



Lead tip -



E1 Plating



Е

D1(3)

Scale: None

SYMBOL	MILLIM	ETERS	INC	INCHES		
STNIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
E	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54	2.54 BSC) BSC		
L	13.46	14.10	0.530	0.555		
L1	-	1.65	-	0.065	3	
L2	3.36	3.71	0.132	0.146		

3. - Anode

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches (6)

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body ⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

Revision: 11-Jul-2019

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